Thyristor Semiconductor Device - Page 1 of 1



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Inclosure	Material:

Plastic

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Height:

0.165 inches

Overall Width:

0.205 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Terminal Circle Diameter:

0.105 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 breakover voltage, dc

Current Rating Per Characteristic:

255.00 milliamperes source cutoff current

Power Rating Per Characteristic:

10.0 milliwatts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnpn

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

80131-release5555 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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